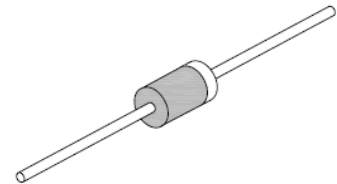


3.0A Sintered Glass Passivated Super Fast Recovery Rectifier

Features

- Sintered glass passivated (SGP) rectifier chip
- Low forward voltage, high current capability
- Low leakage current, high surge current capability
- High temperature soldering guaranteed: 260°C/10 seconds
/.0375" (9.5mm) lead length, 5lbs (2.3kg) tension
- RoHS Compliance



DO-201AD



Mechanical Data

Case:	JEDEC DO-201AD molded plastic body
Epoxy:	Plastic package has UL flammability classification 94V-0
Terminals:	Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity:	Color band denotes cathode end
Weight:	0.04ounces, 1.12 grams

Maximum Ratings and Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless noted otherwise)

Symbol	Description	EGP30A	EGP30B	EGP30D	EGP30G	EGP30J	EGP30K	Unit	Conditions
V_{RRM}	Maximum Repetitive Peak Reverse Voltage	50	100	200	400	600	800	V	
V_{RMS}	Maximum RMS Voltage	35	70	140	280	420	560	V	
V_{DC}	Maximum DC Blocking Voltage	50	100	200	400	600	800	V	
I_{F(AV)}	Maximum Average Forward Rectified Current	3.0						A	0.375" (9.5mm) lead length(Fig.1)
I_{FSM}	Peak Forward Surge Current	125				115		A	8.3ms single half sine-wave superimposed on rated load (JEDEC Method)

3.0A Sintered Glass Passivated Super Fast Recovery Rectifier

EGP30A - EGP30K

Symbol	Description	EGP30A	EGP30B	EGP30D	EGP30G	EGP30J	EGP30K	Unit	Conditions
V_F	Maximum Instantaneous Forward Voltage	0.95			1.25	1.70	2.20	V	I _F =3.0 A
I_R	Maximum DC Reverse Current at Rated DC Blocking Voltage	5						μA	TA=25° C
		120							TA=125° C
T_{rr}	Typical Reverse Recovery Time	35						nS	I _F =0.5A, I _R =1A, I _{rr} =0.25A
C_J	Typical Junction Capacitance	35						pF	V _R =4V, f=1MHz
R_{thJA}	Typical Thermal Resistance	20						°C / W	Note
T_J	Operating Temperature range	-55 to +175						°C	
T_{STG}	Storage Temperature Range	-55 to +175							

Note: Thermal resistance from junction to ambient at 0.375" (9.5mm) lead lengths, P.C.B mounted.

Typical Characteristics Curves

Fig.1-Max. Forward Current Derating Curve

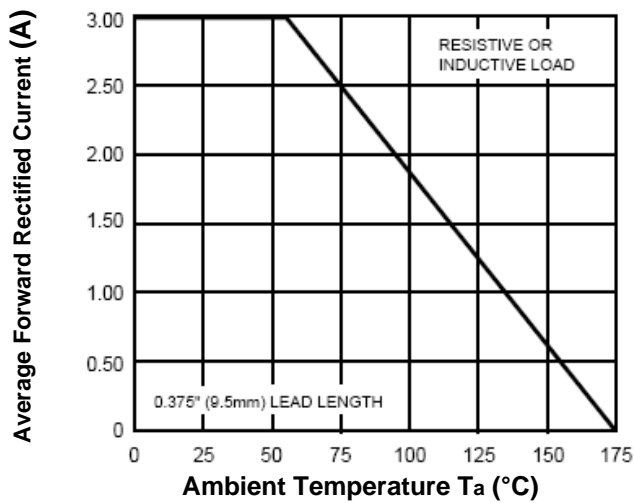
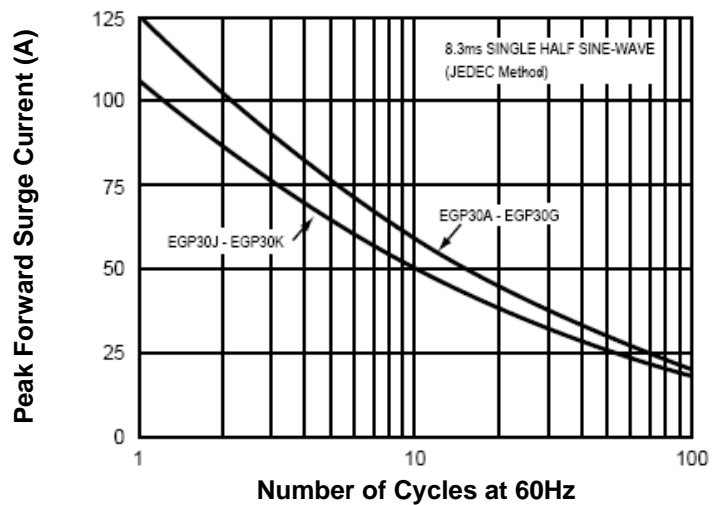


Fig.2-Max. Non-Repetitive Forward Surge Current



3.0A Sintered Glass Passivated Super Fast Recovery Rectifier

EGP30A - EGP30K

Fig.3- Typical Forward Characteristics

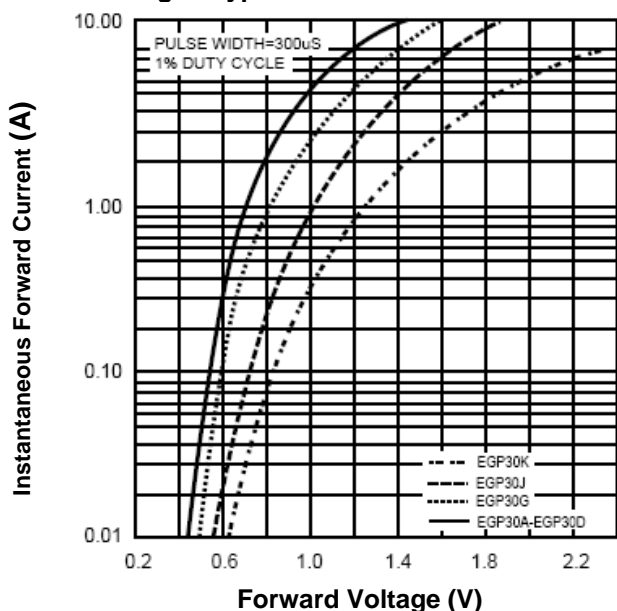


Fig.4-Typical Reverse Characteristics

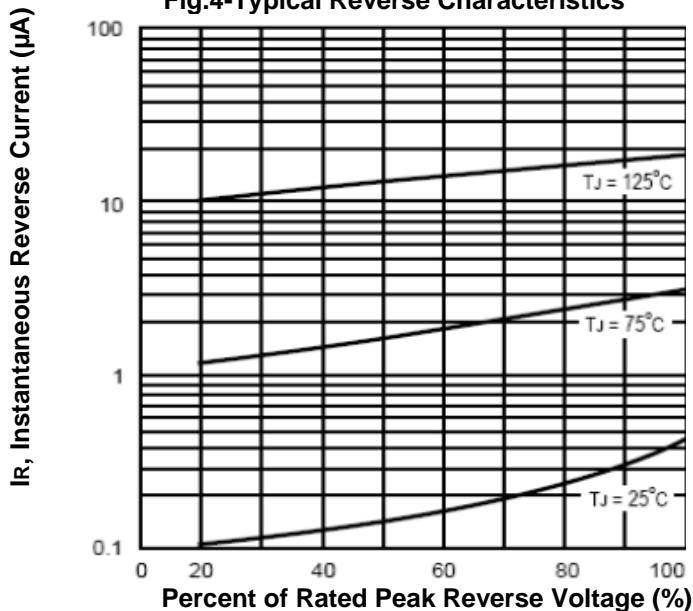
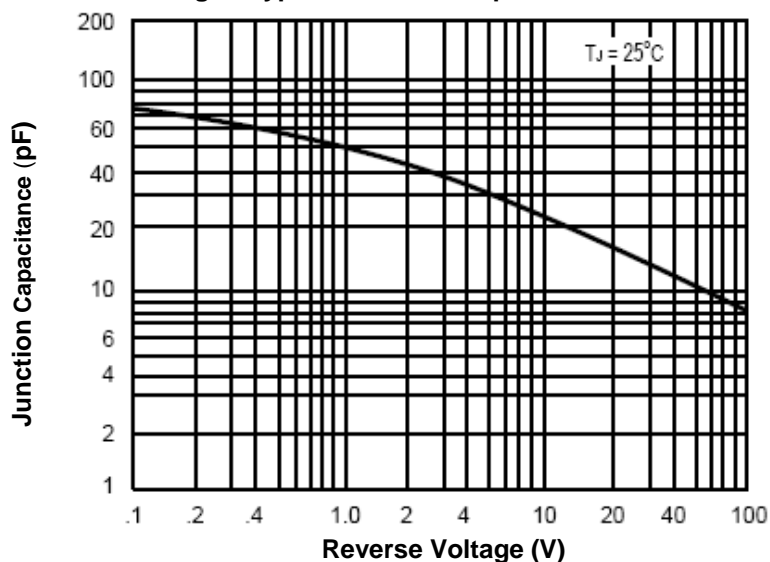


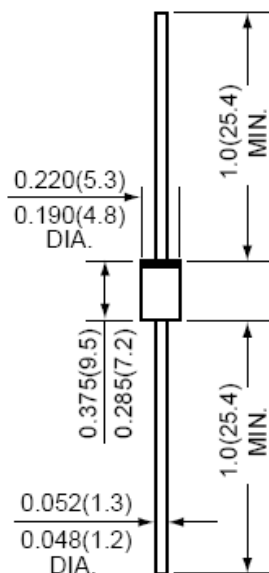
Fig.5- Typical Junction Capacitance



3.0A Sintered Glass Passivated Super Fast Recovery Rectifier

EGP30A - EGP30K

Dimensions in inches (mm)



DO-201AD

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